



# SGMNE12220

## 20V, Power, Single N-Channel, UTDFN Package, MOSFET

### FEATURES

- Low On-State Resistance
- Ultra-Low  $Q_G$  and  $Q_{GD}$
- ESD Diode Protected Gate
- HBM > 2kV
- Ultra-Small Footprint "Tiny FET"

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNITS
Drain-to-Source Voltage	$V_{DS}$	20	V
Gate-to-Source Voltage	$V_{GS}$	$\pm 8$	V
Drain Current <sup>(1)</sup>	$I_D$	$T_A = +25^\circ\text{C}$	2
		$T_A = +70^\circ\text{C}$	1.6
Drain Current (Pulse) <sup>(2)</sup>	$I_{DM}$	4	A
Total Dissipation	$P_D$	$T_A = +25^\circ\text{C}$	690
		$T_A = +70^\circ\text{C}$	440
Junction Temperature	$T_J$	+150	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-55 to +150	$^\circ\text{C}$
Lead Temperature (Soldering, 10s)		+260	$^\circ\text{C}$

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

**NOTES:**

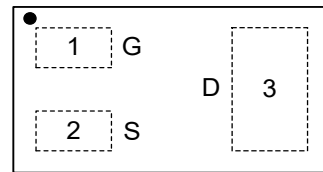
1. The current will be limited by PCB, thermal design and operating temperature.
2.  $t_{PULSE} < 10\mu\text{s}$

### PRODUCT SUMMARY

$R_{DS(ON)}$ (TYP) $V_{GS} = 4.5\text{V}$	$R_{DS(ON)}$ (MAX) $V_{GS} = 4.5\text{V}$	$I_D$ (MAX) $T_A = +25^\circ\text{C}$
100m $\Omega$	125m $\Omega$	2A

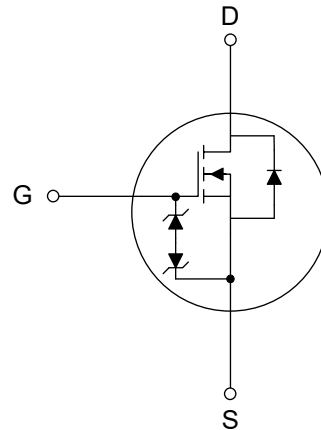
### PIN CONFIGURATION

(TOP VIEW)



UTDFN-1x0.6-3L

### EQUIVALENT CIRCUIT



### APPLICATIONS

- Optimized for Load Switch Applications
- Optimized for General Purpose
- Switching Applications
- Battery Applications
- Handheld and Mobile Applications
- IO Expansion Switch

# SGMNE12220

# 20V, Power, Single N-Channel, UTDFN Package, MOSFET

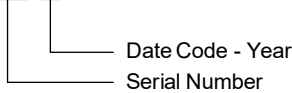
## PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGMNE12220	UTDFN-1×0.6-3L	-55°C to +150°C	SGMNE12220TUEM3G/TR	04X	Tape and Reel, 10000

## MARKING INFORMATION

NOTE: X = Date Code.

**YY X**



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

## ESD SENSITIVITY CAUTION

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

## THERMAL RESISTANCE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNITS
Junction-to-Ambient Thermal Resistance <sup>(1)</sup>	R <sub>θJA</sub>	180	°C/W

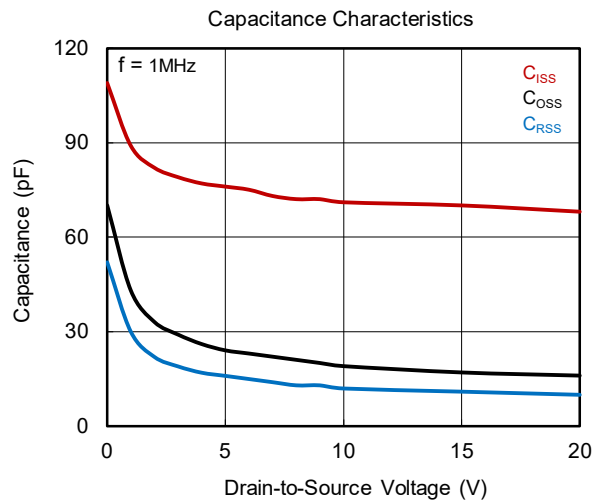
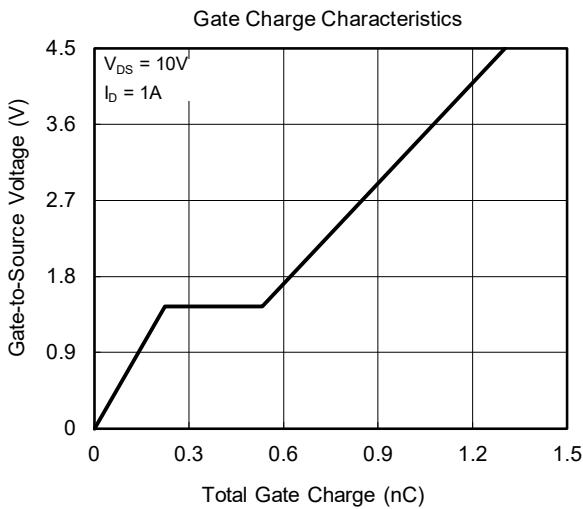
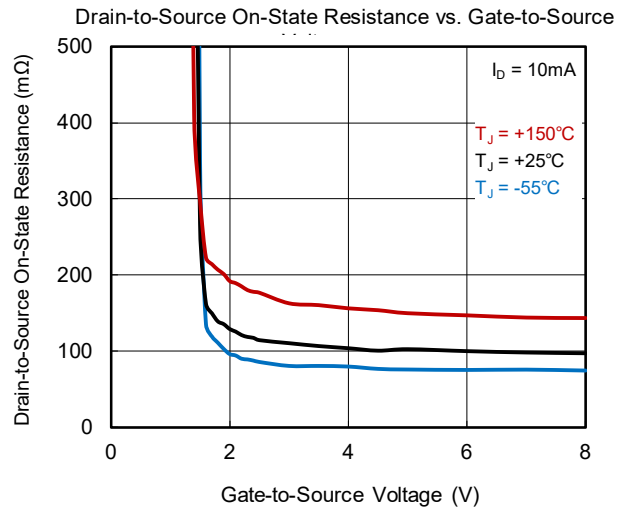
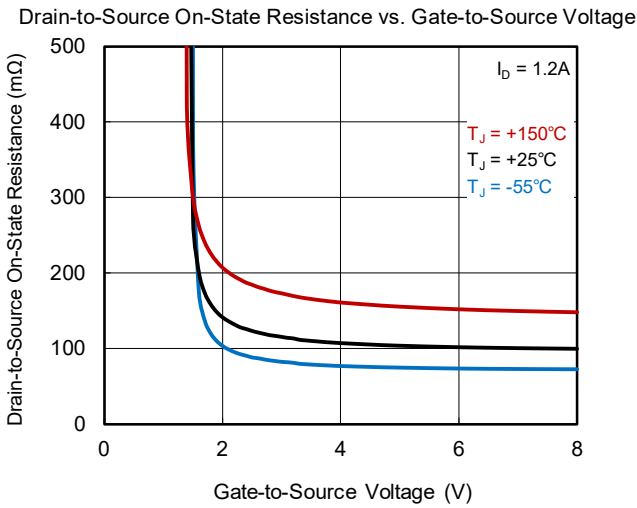
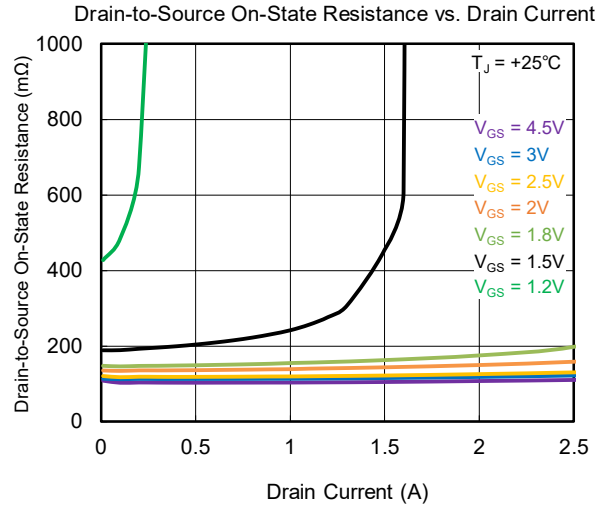
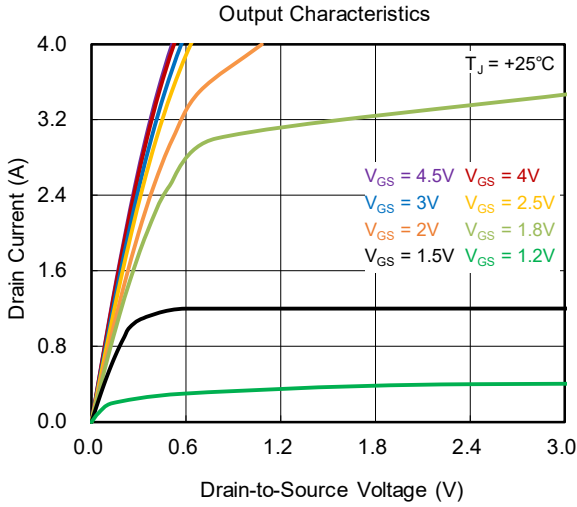
NOTE: 1. R<sub>θJA</sub> is determined with the device mounted on one square inch of copper pad, 2oz copper on FR4 board.

**ELECTRICAL CHARACTERISTICS**(T<sub>A</sub> = +25°C, unless otherwise noted.)

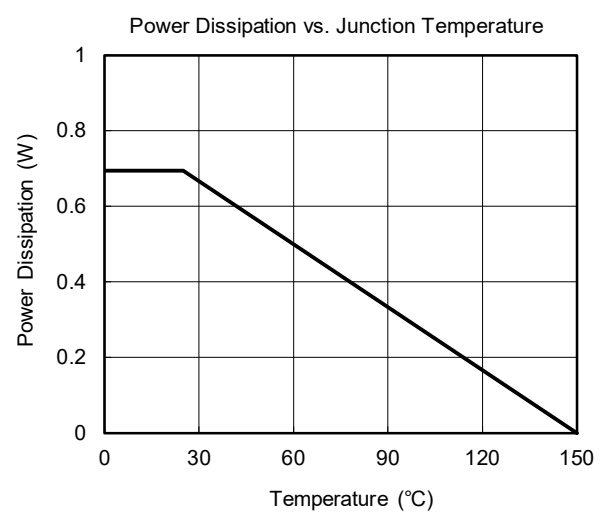
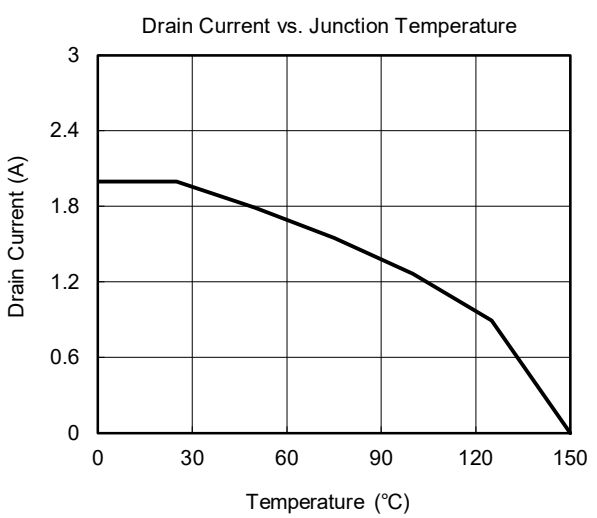
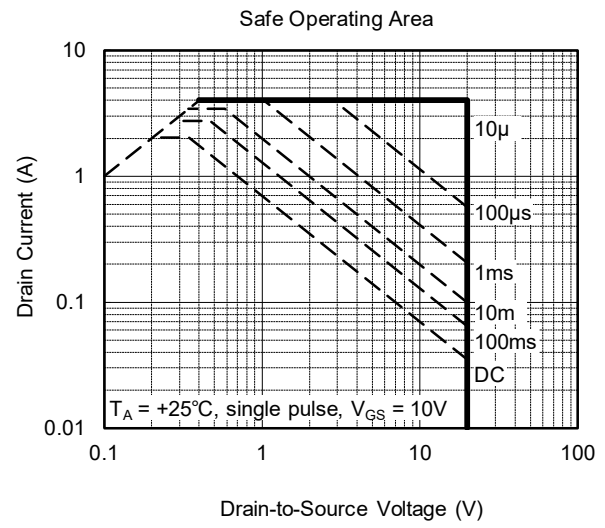
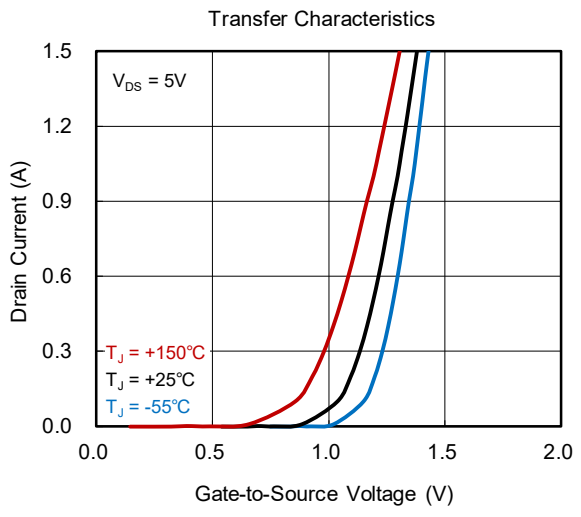
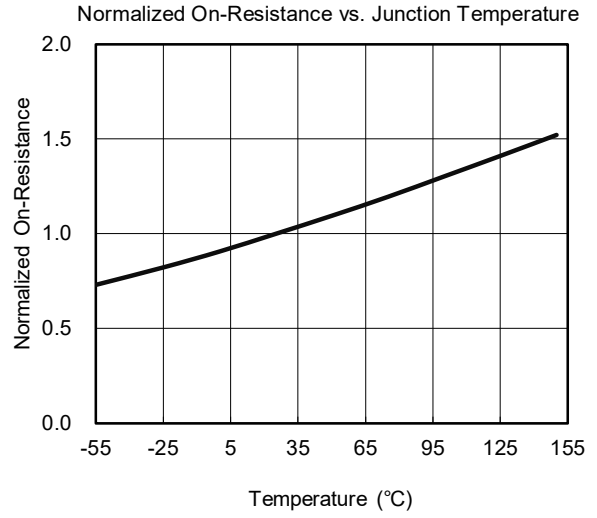
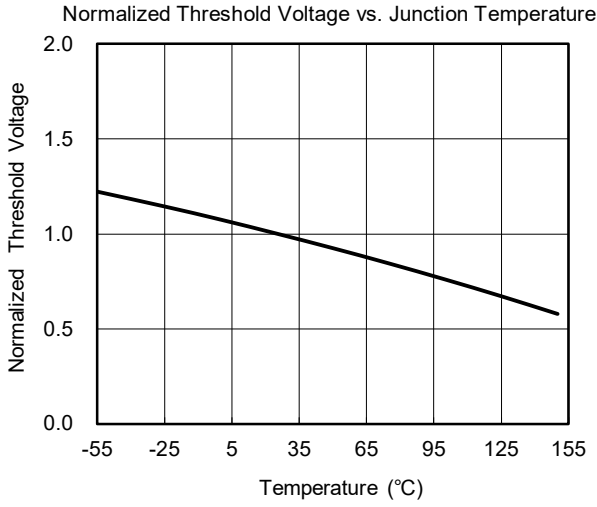
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
<b>Static OFF Characteristics</b>						
Drain-to-Source Breakdown Voltage	V <sub>BR_DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	20			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 20V			1	μA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±8V, V <sub>DS</sub> = 0V			±10	μA
<b>Static ON Characteristics</b>						
Gate Threshold Voltage	V <sub>GS_TH</sub>	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250μA	0.4	0.7	1	V
Static Drain-to-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 1.2A		100	125	mΩ
		V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 1A		115	155	
		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 0.35A		145	190	
		V <sub>GS</sub> = 1.5V, I <sub>D</sub> = 0.01A		181	360	
		V <sub>GS</sub> = 1.2V, I <sub>D</sub> = 0.01A		400	800	
<b>Diode Characteristics</b>						
Forward Diode Voltage	V <sub>F_SD</sub>	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1A		0.9	1.2	V
<b>Dynamic Characteristics</b>						
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 10V, f = 1MHz		71		pF
Output Capacitance	C <sub>OSS</sub>			20		
Reverse Transfer Capacitance	C <sub>RSS</sub>			12		
Total Gate Charge	Q <sub>G</sub>	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 1A		1.3		nC
Gate-to-Source Charge	Q <sub>GS</sub>			0.2		
Gate-to-Drain Charge	Q <sub>GD</sub>			0.3		
<b>Switch Characteristics</b>						
Turn-On Delay Time	t <sub>D_ON</sub>	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 1A, R <sub>G</sub> = 3Ω		8		ns
Rise Time	t <sub>R</sub>			25		
Turn-Off Delay Time	t <sub>D_OFF</sub>			40		
Fall Time	t <sub>F</sub>			33		

NOTE: 1. Please contact sales for SPICE Model support.

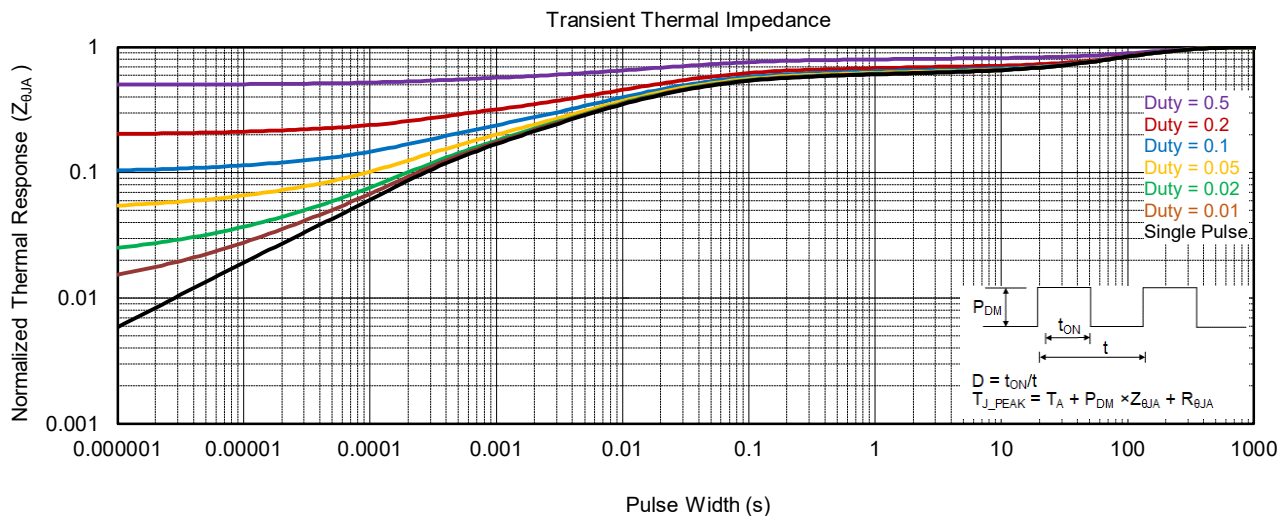
TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



REVISION HISTORY

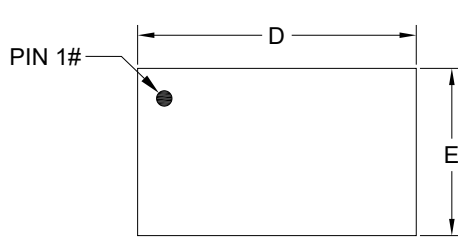
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (DECEMBER 2024) to REV.A	Page
Changed from product preview to production data.....	All

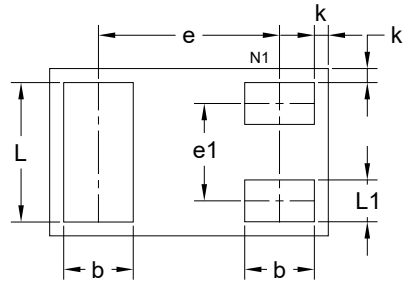
# PACKAGE INFORMATION

## PACKAGE OUTLINE DIMENSIONS

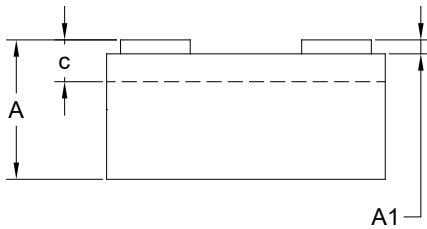
### UTDFN-1×0.6-3L



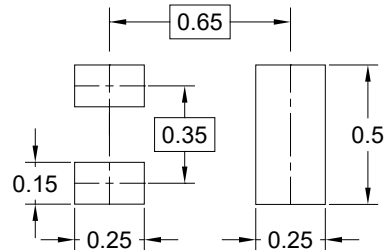
TOP VIEW



BOTTOM VIEW



SIDE VIEW



RECOMMENDED LAND PATTERN (Unit: mm)

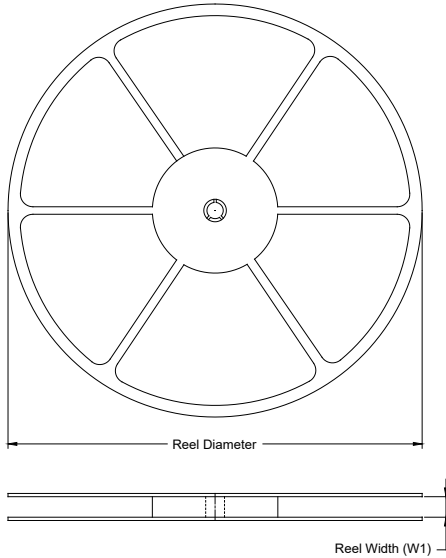
Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	0.450	0.500	0.550
A1	0.000	-	0.050
b	0.200	0.250	0.300
c	0.120	0.150	0.180
D	0.950	1.000	1.050
E	0.550	0.600	0.650
e	0.650 BSC		
e1	0.350 BSC		
k	0.050 REF		
L	0.450	0.500	0.550
L1	0.100	0.150	0.200

NOTE: This drawing is subject to change without notice.

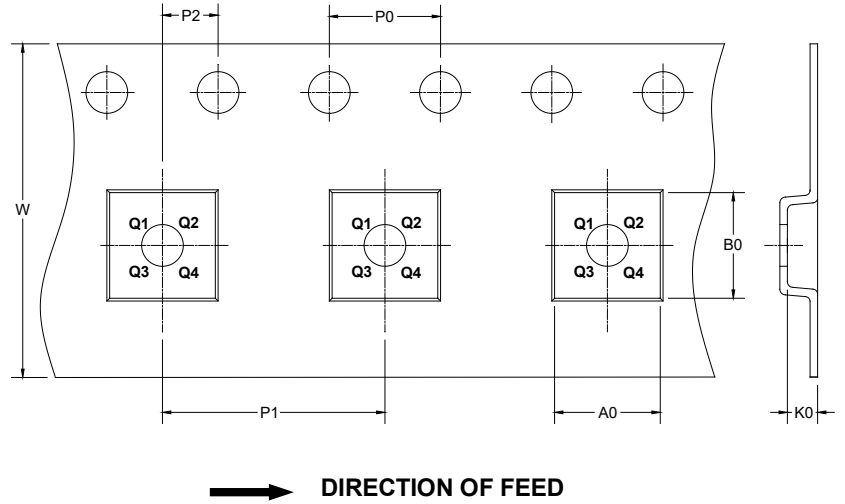
# PACKAGE INFORMATION

## TAPE AND REEL INFORMATION

### REEL DIMENSIONS



### TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF TAPE AND REEL

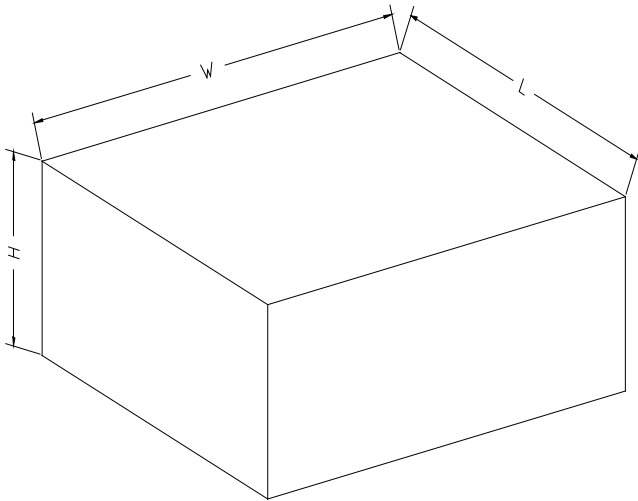
Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
UTDFN-1×0.6-3L	7"	8.6	0.70	1.15	0.57	4.0	2.0	2.0	8.0	Q2

DD0001



# PACKAGE INFORMATION

## CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

## KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18

DD0002